



# **DC/DC Converter Applications**

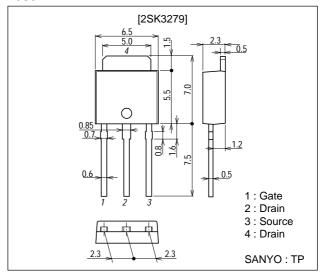
#### **Preliminary**

#### **Features**

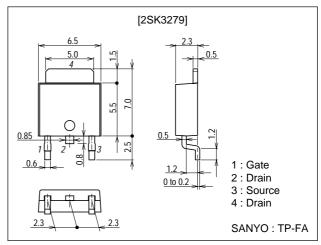
- · Low ON resistance.
- 4V-drive.
- · Ultrahigh-spped switching.

### **Package Dimensions**

unit : mm 2083B



unit : mm 2092B



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## **Specifications**

## Absolute Maximum Ratings at Ta=25 $^{\circ} C$

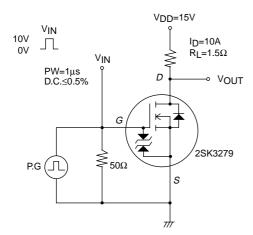
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		15	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	45	Α
Allowable Power Dissipation	PD		1	W
		Tc=25°C	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	30			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0		2.4	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =10A	9	14		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =10A, V <sub>G</sub> S=10V		22	29	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =4A, V <sub>G</sub> S=4.5V		30	42	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		750		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		300		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		120		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit		10		ns
Rise Time	tr	See specified Test Circuit		220		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit		48		ns
Fall Time	tf	See specified Test Circuit		61		ns
Total Gate Charge	Qg	VDS=10V, VGS=10V, ID=15A		14		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =15A		2.5		nC
Gate-to-Drain "Miller"Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =15A		1.3		nC
Diode Forward Voltage	VsD	IS=15A, VGS=0		0.93	1.2	V

Marking: K3283

### **Switching Time Test Circuit**



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